

#### **Product Description**

Stanford Microdevices' SCA-15 is a high performance Gallium Arsenide Hetrojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration is utilized for broadband performance up to 3 GHz. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Typical IP3 at 50mA is +27dBm.

These unconditionally stable amplifiers provides up to 12dB of gain and +13.5dBm of 1dB compressed power and requires only a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional inductor are needed for operation.

This MMIC is an ideal choice for wireless applications such as cellular, PCS, CDPD, wireless data and SONET.

# Output IP3 vs. Frequency 30 28 dBm 24 22 20 0.1 1 2 GHz

#### **SCA-15**

## DC-3 GHz, Cascadable GaAs HBT MMIC Amplifier



#### **Product Features**

• High Output IP3: +27dBm

Flat Gain: +/- 0.5dB Over Full Band
 Cascadable 50 Ohm: 1.5:1 VSWR

Patented GaAs HBT Technology

Operates From Single Supply

Low Thermal Resistance Package

#### **Applications**

• Cellular, PCS, CDPD

Wireless Data, SONET

#### Electrical Specifications at Ta = 25C

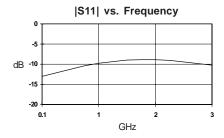
Symbol	Param eters: Test Conditions: Id = 50 m A, Z <sub>o</sub> = 50 O hm s		Units	Min.	Тур.	Мах.
G <sub>P</sub>	Power Gain	f = 0.1-2.0 G H z f = 2.0-3.0 G H z	d B d B	10	1 2 11	
G <sub>F</sub>	Gain Flatness Gain Flatness over any 100 MHz band	f = 0.1-2.0 GHz	d B d B		+/- 0.5 +/- 0.1	
P <sub>1 d B</sub>	Output Power at 1dB Compression	f = 0.1-2.0 GHz	d B m		13.5	
NF	Noise Figure	f = 0.1-3.0 GHz	d B		6.0	
VSWR	Input and Output VSWR	f = 0.1-3.0 GHz	-		1.5	
IP <sub>3</sub>	Third Order Intercept Point Output Tone @ 0dBm 10 MHz Apart	f = 0.1-2.0 GHz	d B m		27.0	
T <sub>D</sub>	Group Delay	f = 1.9 GHz	psec		100	
ISOL	Reverse Isolation	f = 0.1-3.0 GHz	d B		16	
V D	Device Voltage		V	3.5	4.0	4.5
dG/dT	Device Gain Temperature Coefficient		dB/degC		0.0015	
dV/dT	Device Voltage Temperature Coefficient		m V/degC		-4.0	

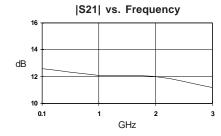
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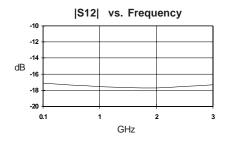


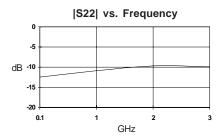
#### SCA-15 DC-3 GHz Cascadable MMIC Amplifier

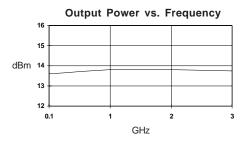
#### Typical Performance at 25° C (Vds = 4.0V, Ids = 50mA)











Typical S-Parameters Vds = 4.0V, Id = 50mA

Freq GHz	S11	S11 Ang	S21	S21 Ang	S12	S12 Ang	S22	S22 Ang
.100	0.284	125	4.182	152	0.143	-24	0.235	131
.500	0.297	119	4.170	138	0.139	-33	0.249	119
.900	0.320	73	4.042	107	0.135	-58	0.276	75
1.00	0.327	62	4.025	98	0.136	-64	0.285	63
1.50	0.354	8	3.948	60	0.133	-96	0.319	10
2.00	0.360	-44	3.983	21	0.130	-125	0.338	-43
2.50	0.344	-97	3.777	-20	0.133	-157	0.339	-97
3.00	0.307	-152	3.618	-55	0.137	-167	0.320	-151

(S-Parameters include the effects of two 1.0 mil diameter bond wires, each 20 mils long, connected to the gate and drain pads on the die)

522 Almanor Ave., Sunnyvale, CA 94086 Phone: (800) SMI-MMIC



#### **Absolute Maximum Ratings**

Parameter	A b solute M a x im u m		
Device Current	75 m A		
Power Dissipation	350 m W		
RF Input Power	100 m W		
Junction Temperature	+200C		
Operating Temperature	-45C to +85C		
Storage Temperature	-65C to +150C		

#### Notes:

1. Operation of this device above any one of these parameters may cause permanent damage.

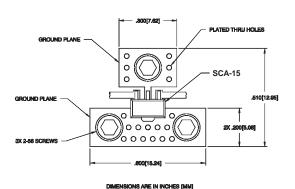
Recommended Bias Resistor Values						
Supply Voltage (Vs)	5V	7.5V	9V	12V	15V	20V
Rbias (Ohms)	20	70	100	160	220	320

#### **Mounting Instructions**

The data shown was taken on a 31mil thick FR-4 board with 1 ounce of copper on both sides.

The board was mounted to a baseplate with 3 screws as shown. The screws bring the top side copper temperature to the same value as the baseplate.

- 1. Use 1 or 2 ounce copper, if possible.
- 2. Solder the copper pad on the backside of the device package to the ground plane.
- 3. Use a large ground pad area with many plated through-holes as shown.
- 4. If possible, use at least one screw no more than 0.2 inch from the device package to provide a low thermal resistance path to the baseplate of the package.
- 5. Thermal resistance from ground lead to screws is
- 2 deg. C/W.

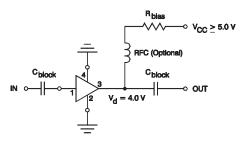


#### SCA-15 DC-3 GHz Cascadable MMIC Amplifier

### MTTF vs. Temperature @ Id = 100mA

Lead Temperature	MTTF (hrs)
+55C	1,000,000
+90C	100,000
+120C	10,000

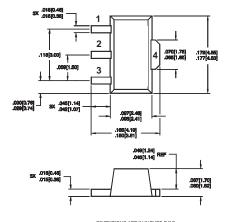
Thermal Resistance (Lead-Junction): 510° C/W



**Typical Biasing Configuration** 

Pin Designation			
1	RF in		
2	GND		
3	RF out and Bias		
4	GND		

#### **Outline Drawing**



DIMENSIONS ARE IN INCHES [MM]
Ph easignments shown for reference only, not marked on part

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